

MBR130HW

Technical Data Data Sheet N0716, Rev. B



MBR130HW SURFACE MOUNT SCHOTTKY BARRIER DIODE



Features

- Low Turn-on Voltage
- Fast Switching
- PN Junction Guard Ring Transient and ESD Protection
- Designed for Surface Mount Application
- Plastic Material —UL Recognition Flammability Classification 94V-O
- Green Products in Compliance with the ROHS Directive
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Data

- Case: SOD-123, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.01 grams(approx)

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

| Characteristic | Symbol | MBR130HW | Unit |
|--|--|-------------|------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | 30 | V |
| Forward Continuous Current(Note1) | lF | 1.0 | А |
| Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load(JEDEC Method) | I _{FSM} | 25 | А |
| Power Dissipation(Note1) | PD | 450 | mW |
| Typical Thermal Resistance, Junction to Ambient Air(Note1) | R _{eja} | 222 | °C/W |
| Junction and Storage Temperature Range | Tj, Tstg | -65 to +125 | °C |

| Characteristic | | Symbol | Тур. | Max. | Unit |
|---|----------|-----------------|------|------|------|
| Forward Voltage Drop | @I⊧=1.0A | Vfm | 0.44 | 0.45 | V |
| Peak Reverse Leakage Current @DC Blocking Voltage | | I _{RM} | 0.01 | 0.4 | mA |
| Junction Capacitance(V _R =4V DC, f=1MHz) | | CJ | 50 | - | pF |

Note: 1. Valid provided that terminals are kept at ambient temperature.

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Circuit Diagram



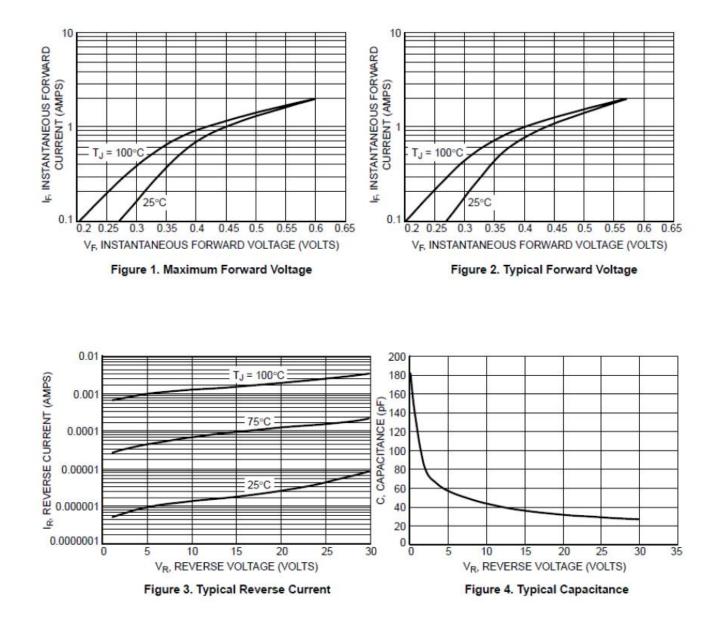


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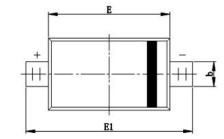
Ratings and Characteristics Curves

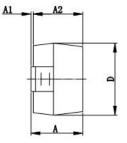


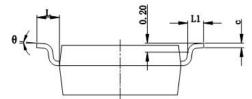


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Mechanical Dimensions SOD-123







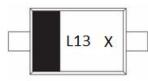
| | Millimeters | | Inches | |
|--------|-------------|-------|------------|-------|
| SYMBOL | MIN. | MAX. | MIN. | MAX. |
| A | 1.050 | 1.250 | 0.041 | 0.049 |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 |
| A2 | 1.050 | 1.150 | 0.041 | 0.045 |
| b | 0.450 | 0.650 | 0.018 | 0.026 |
| с | 0.080 | 0.150 | 0.003 | 0.006 |
| D | 1.500 | 1.700 | 0.059 | 0.067 |
| E | 2.600 | 2.800 | 0.102 | 0.110 |
| E1 | 3.550 | 3.850 | 0.140 | 0.152 |
| L | 0.500 REF. | | 0.020 REF. | |
| L1 | 0.250 | 0.450 | 0.010 | 0.018 |
| θ | 0° | 8° | 0° | 8° |

Ordering Information

| Device | Package | Shipping |
|----------|----------------------|----------------|
| MBR130HW | SOD-123 (Pb-Free) | 3000pcs / reel |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

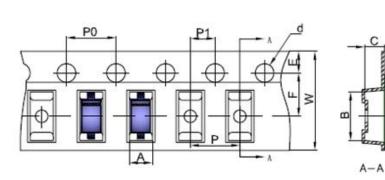
Marking Diagram



Where X is Date Code L13 = Part Name

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Carrier Tape Specification SOD-123



| SYMBOL | Millimeters | | |
|--------|-------------|------|--|
| STWBOL | Min. | Max. | |
| А | 1.80 | 1.90 | |
| В | 3.89 | 3.99 | |
| С | 1.52 | 1.62 | |
| d | 1.45 | 1.65 | |
| E | 1.65 | 1.85 | |
| F | 3.40 | 3.60 | |
| Р | 3.90 | 4.10 | |
| P0 | 3.90 | 4.10 | |
| P1 | 1.90 | 2.10 | |
| W | 7.90 | 8.30 | |

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